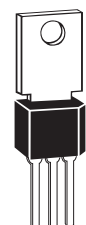
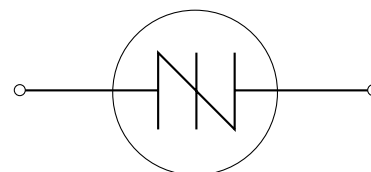


DO-15X

DO-214
Surface Mount

TO-202

TO-92
Type 70

Sidac

(79 V to 330 V) RoHS

General Description

The sidac is a silicon bilateral voltage triggered switch with greater power-handling capabilities than standard diacs. Upon application of a voltage exceeding the sidac breakover voltage point, the sidac switches on through a negative resistance region to a low on-state voltage. Conduction continues until the current is interrupted or drops below the minimum holding current of the device.

Teccor's sidacs feature glass-passivated junctions to ensure a rugged and dependable device capable of withstanding harsh environments.

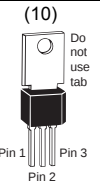
Variations of devices covered in this data sheet are available for custom design applications. Consult the factory for more information.

Applications

- High-voltage lamp ignitors
- Natural gas ignitors
- Gas oil ignitors
- High-voltage power supplies
- Xenon ignitors
- Overvoltage protector
- Pulse generators
- Fluorescent lighting ignitors
- HID lighting ignitors

Features

- RoHS Compliant
- AC circuit oriented
- Glass-passivated junctions
- High surge current capability

Type	Part No.				$I_{T(RMS)}$	V_{DRM}	V_{BO}		I_{DRM}	I_{BO}	I_H	
	 TO-92	 DO-15X	 TO-202	 DO-214	(6) (7) (8) Amps	Volts	(1) Volts		μAmps	μAmps	(3) (4) mAmps	
See "Package Dimensions" section for variations. (9)					MAX	MIN	MIN	MAX	MAX	MAX	TYP	MAX
	K0900E70	K0900G		K0900S	1	±70	79	97	5	10	60	150
	K1050E70	K1050G		K1050S	1	±90	95	113	5	10	60	150
	K1100E70	K1100G		K1100S	1	±90	104	118	5	10	60	150
	K1200E70	K1200G		K1200S	1	±90	110	125	5	10	60	150
	K1300E70	K1300G		K1300S	1	±90	120	138	5	10	60	150
	K1400E70	K1400G		K1400S	1	±90	130	146	5	10	60	150
	K1500E70	K1500G		K1500S	1	±90	140	170	5	10	60	150
	K2000E70	K2000G	K2000F1	K2000S	1	±180	190	215	5	10	60	150
	K2200E70	K2200G	K2200F1	K2200S	1	±180	205	230	5	10	60	150
	K2400E70	K2400G	K2400F1	K2400S	1	±190	220	250	5	10	60	150
			K2401F1		(11)	±190	220	250	5	10	60	150
	K2500E70	K2500G	K2500F1	K2500S	1	±200	240	280	5	10	60	150
			K3000F1		1	±200	270	330	5	10	60	150

Specific Test Conditions

di/dt — Critical rate-of-rise of on-state current

dv/dt — Critical rate-of-rise of off-state voltage at rated V_{DRM} ;
 $T_J \leq 100^\circ\text{C}$

dV_q/dt — Critical rate-of-rise of turn-off voltage at 8 kHz

I_{BO} — Breakover current 50/60 Hz sine wave

I_{DRM} — Repetitive peak off-state current 50/60 Hz sine wave; $V = V_{DRM}$

I_H — Dynamic holding current 50/60 Hz sine wave; $R = 100\ \Omega$

$I_{T(RMS)}$ — On-state RMS current $T_J \leq 125^\circ\text{C}$ 50/60 Hz sine wave

I_{TSM} — Peak one-cycle surge current 50/60 Hz sine wave (non-repetitive)

R_S — Switching resistance $R_S = \frac{(V_{BO} - V_S)}{(I_S - I_{BO})}$ 50/60 Hz sine wave

V_{BO} — Breakover voltage 50/60 Hz sine wave

V_{DRM} — Repetitive peak off-state voltage

V_{TM} — Peak on-state voltage; $I_T = 1\ \text{A}$

General Notes

- All measurements are made at 60 Hz with a resistive load at an ambient temperature of $+25^\circ\text{C}$ unless otherwise specified.
- Storage temperature range (T_S) is -65°C to $+150^\circ\text{C}$.
- The case (T_C) or lead (T_L) temperature is measured as shown on the dimensional outline drawings in the "Package Dimensions" section of this catalog.
- Junction temperature range (T_J) is -40°C to $+125^\circ\text{C}$.
- Lead solder temperature is a maximum of $+230^\circ\text{C}$ for 10 s maximum; $\geq 1/16"$ (1.59 mm) from case.

Electrical Specification Notes

- See Figure E9.5 for V_{BO} change versus junction temperature.
- See Figure E9.6 for I_{BO} versus junction temperature.
- See Figure E9.2 for I_H versus case temperature.
- See Figure E9.13 for test circuit.

- See Figure E9.1 for more than one full cycle rating.

- $T_C \leq 90^\circ\text{C}$ for TO-92 Sidac
 $T_C \leq 105^\circ\text{C}$ for TO-202 Sidacs
 $T_L \leq 100^\circ\text{C}$ for DO-15X
 $T_L \leq 90^\circ\text{C}$ for DO-214

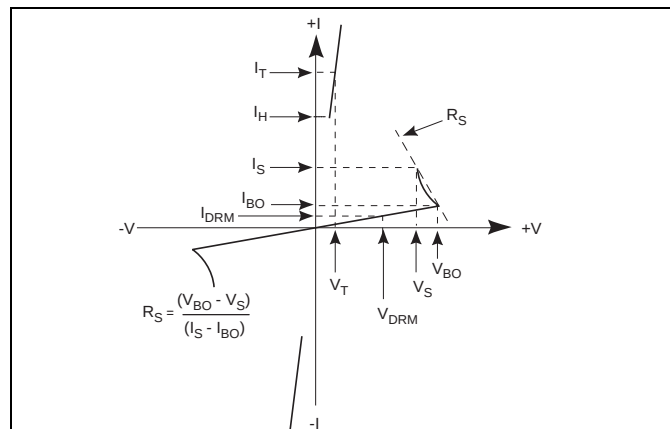
- See Figure E9.14 for clarification of sidac operation.

- For best sidac operation, the load impedance should be near or less than switching resistance.

- See package outlines for lead form configurations. When ordering special lead forming, add type number as suffix to part number.

- Do not use electrically connected mounting tab or center lead.

- The K2401F1 sidac is designed to ensure good commutation at higher switching frequencies, as required in ignitor circuits for high intensity discharge (HID) lighting. A typical circuit for a metal halide lamp ignitor is shown in Figure E9.17. With proper component selection this circuit will produce three pulses for ignition of Osram lamp types such as HQI-T70W, HQI-T150W, and HQI-T250W which require a minimum of three pulses at 4 kV magnitude and $>1\ \mu\text{s}$ duration each at a minimum repetition rate of 3.3 kHz.



V-I Characteristics

LK

V_{TM}				I_{TSM}		R_S	dV_q/dt	dv/dt	di/dt
Volts MAX				(5) Amps		(8) k Ω			
Package				60 Hz	50 Hz		Volts/ μ Sec	Volts/ μ Sec	Amps/ μ Sec
E	G	F	S			MIN	MIN	MIN	TYP
1.5	1.5		1.5	20	16.7	0.1	20	1500	150
1.5	1.5		1.5	20	16.7	0.1	20	1500	150
1.5	1.5		1.5	20	16.7	0.1	20	1500	150
1.5	1.5		1.5	20	16.7	0.1	20	1500	150
1.5	1.5		1.5	20	16.7	0.1	20	1500	150
1.5	1.5		1.5	20	16.7	0.1	20	1500	150
1.5	1.5		1.5	20	16.7	0.1	20	1500	150
1.5	1.5	3	1.5	20	16.7	0.1	20	1500	150
1.5	1.5	3	1.5	20	16.7	0.1	20	1500	150
1.5	1.5	3	1.5	20	16.7	0.1	20	1500	150
		3.3		20	16.7	2	42	1500	150
1.5	1.5	3	1.5	20	16.7	0.1	20	1500	150
		3		20	16.7	0.1	20	1500	150

Thermal Resistance (Steady State) $R_{\theta JC}$ [$R_{\theta JA}$] °C/W (TYPICAL) *			
E Package 	G Package 	F Package 	S Package 
35 [95]	18 [75]	7 [45] **	30 *** [85]

* See Electrical Specification Note (6).

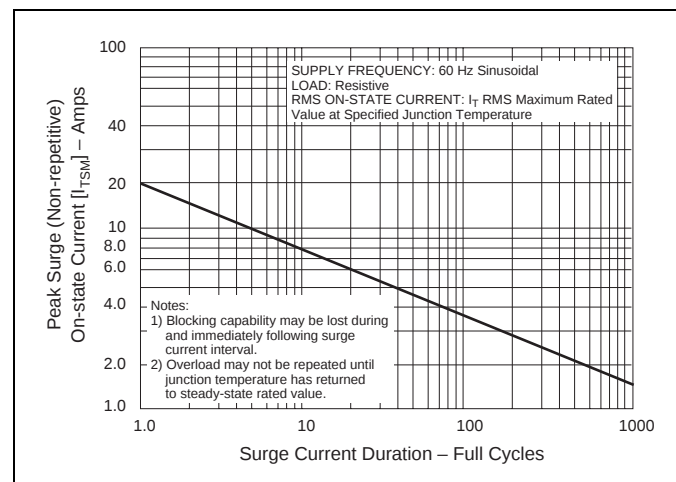
** $R_{\theta JA}$ for TO-202 Type 23 and Type 41 is 70 °C/Watt.*** Mounted on 1 cm² copper foil surface; two-ounce copper foil

Figure E9.1 Peak Surge Current versus Surge Current Duration

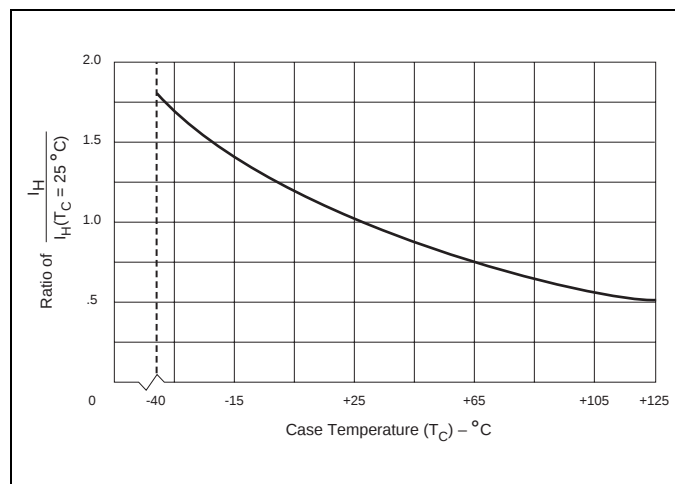


Figure E9.2 Normalized DC Holding Current versus Case/Lead Temperature

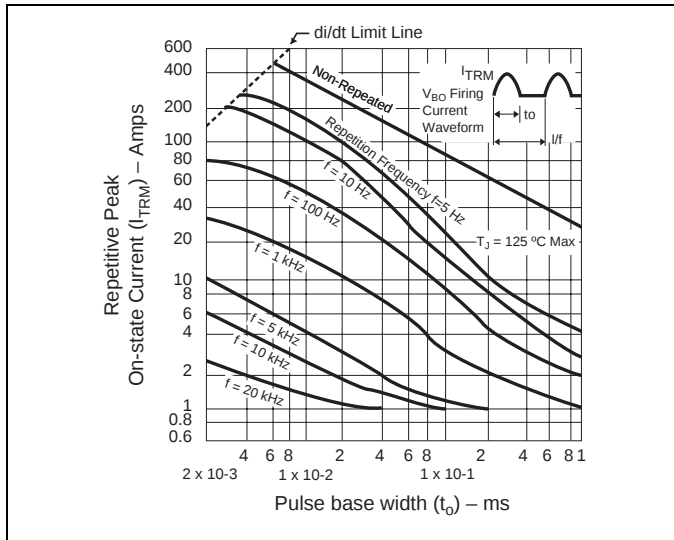


Figure E9.3 Repetitive Peak On-state Current (I_{TRM}) versus Pulse Width at Various Frequencies

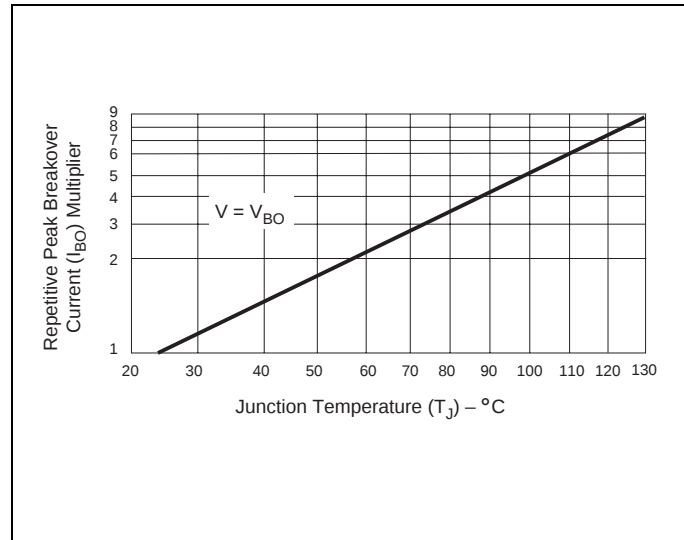


Figure E9.6 Normalized Repetitive Peak Breakover Current versus Junction Temperature

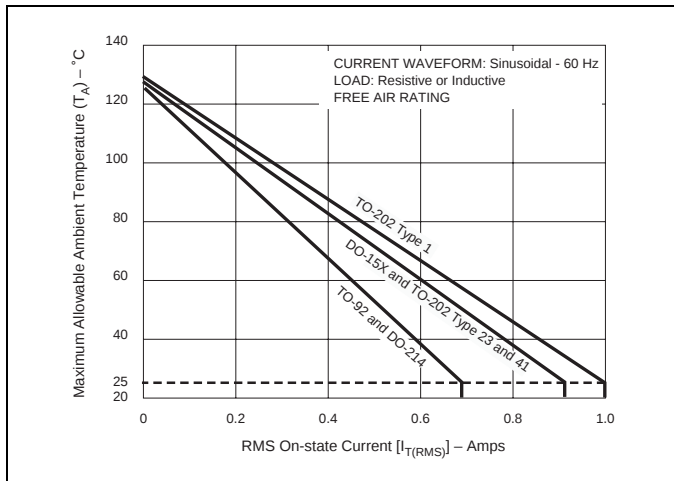


Figure E9.4 Maximum Allowable Ambient Temperature versus On-state Current

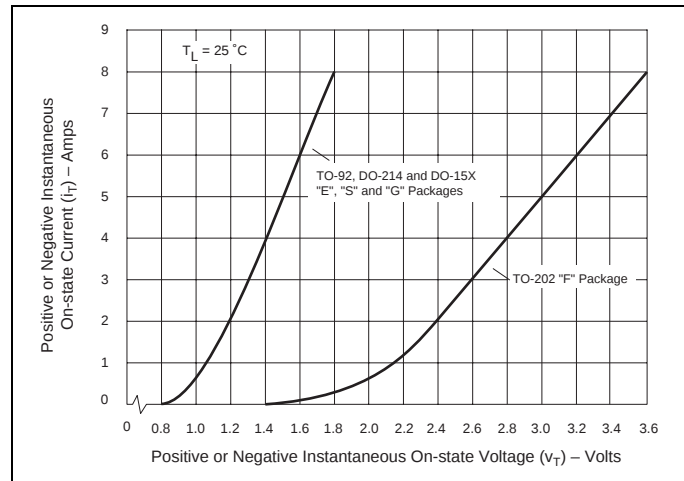


Figure E9.7 On-state Current versus On-state Voltage (Typical)

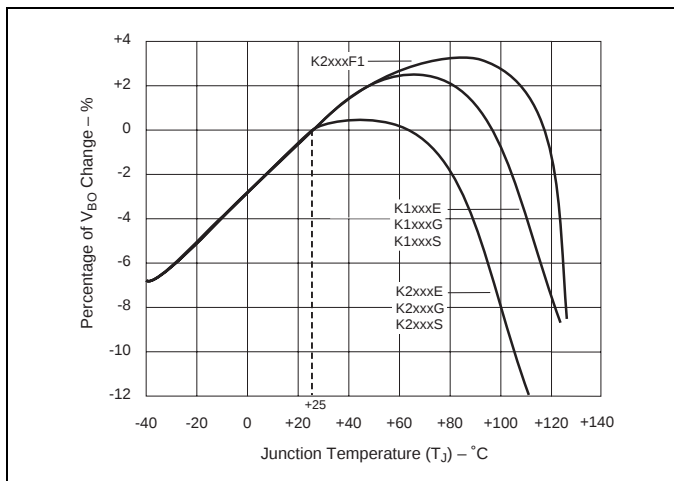


Figure E9.5 Normalized V_{BO} Change versus Junction Temperature

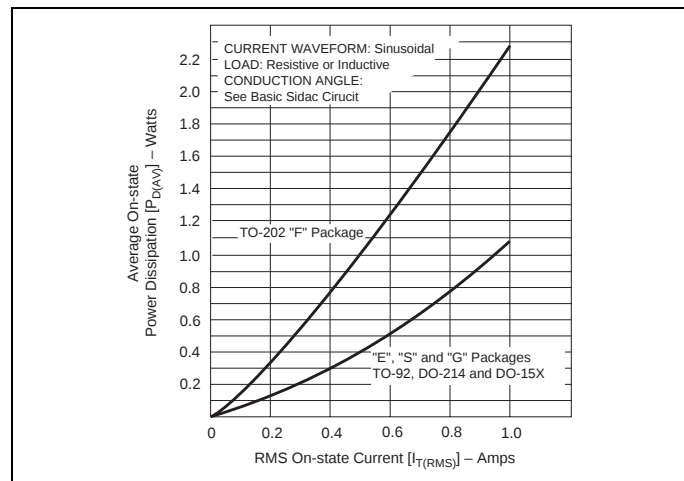


Figure E9.8 Power Dissipation (Typical) versus On-state Current [Refer to Figure E9.14 for Basic Sidac Circuit]

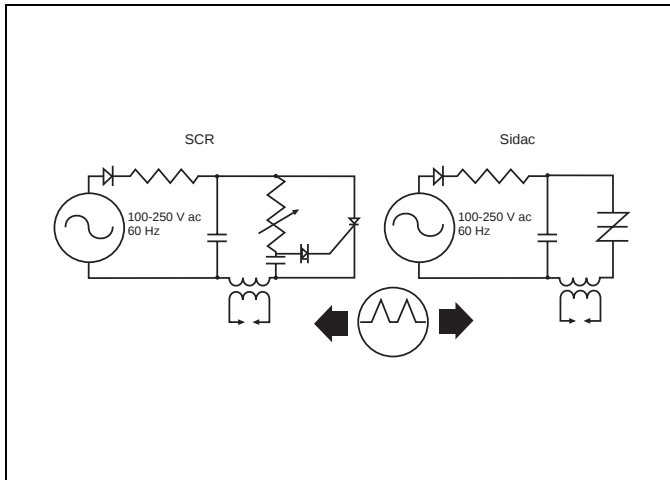


Figure E9.9 Comparison of Sidac versus SCR for Gas Ignitor Circuit

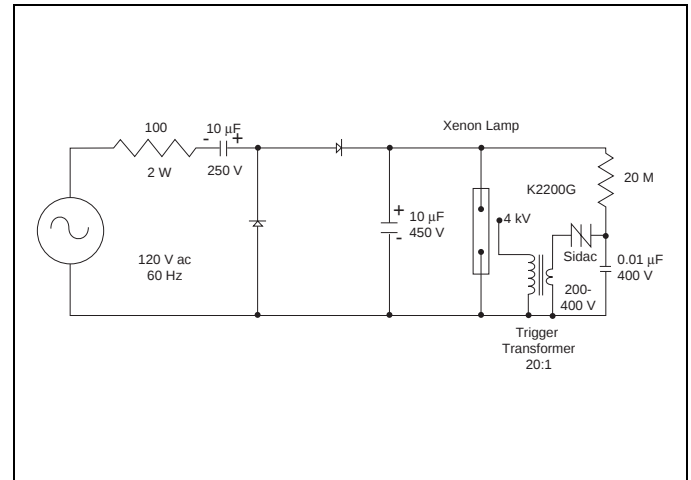


Figure E9.12 Xenon Lamp Flashing Circuit

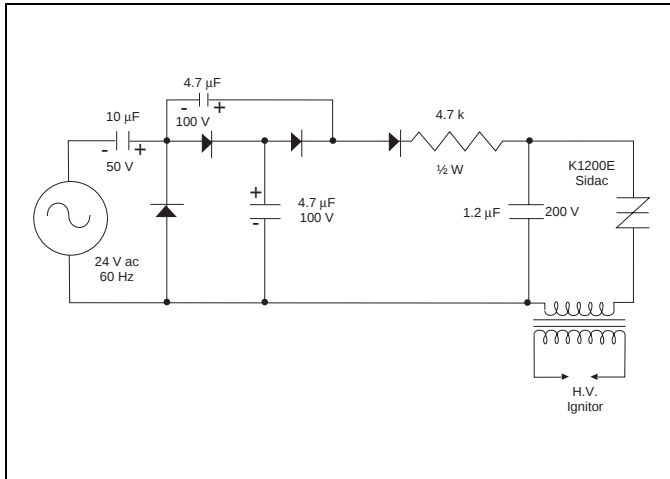


Figure E9.10 Circuit (Low Voltage Input) for Gas Ignition

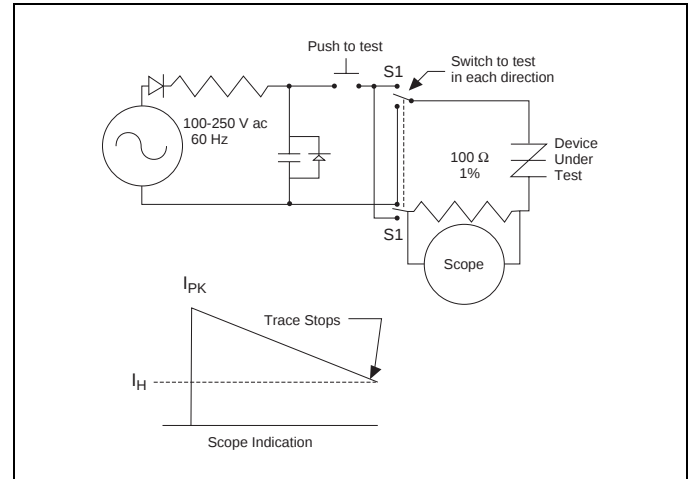


Figure E9.13 Dynamic Holding Current Test Circuit for Sidacs

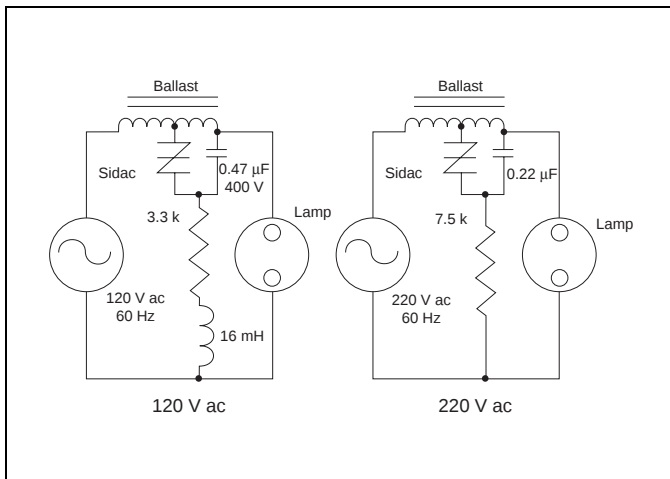


Figure E9.11 Typical High Pressure Sodium Lamp Firing Circuit

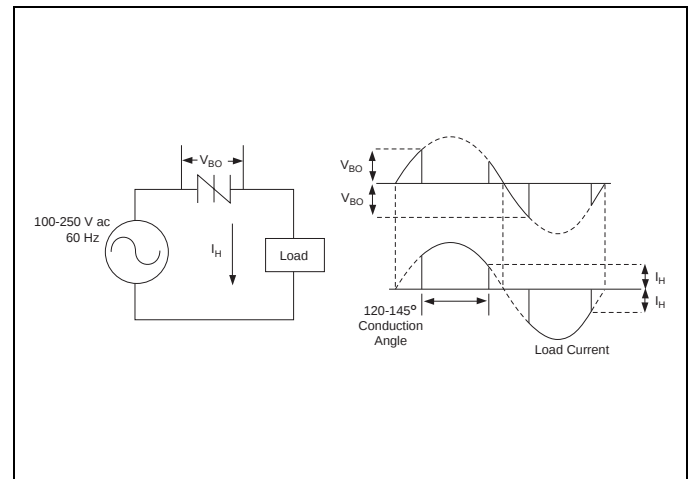


Figure E9.14 Basic Sidac Circuit

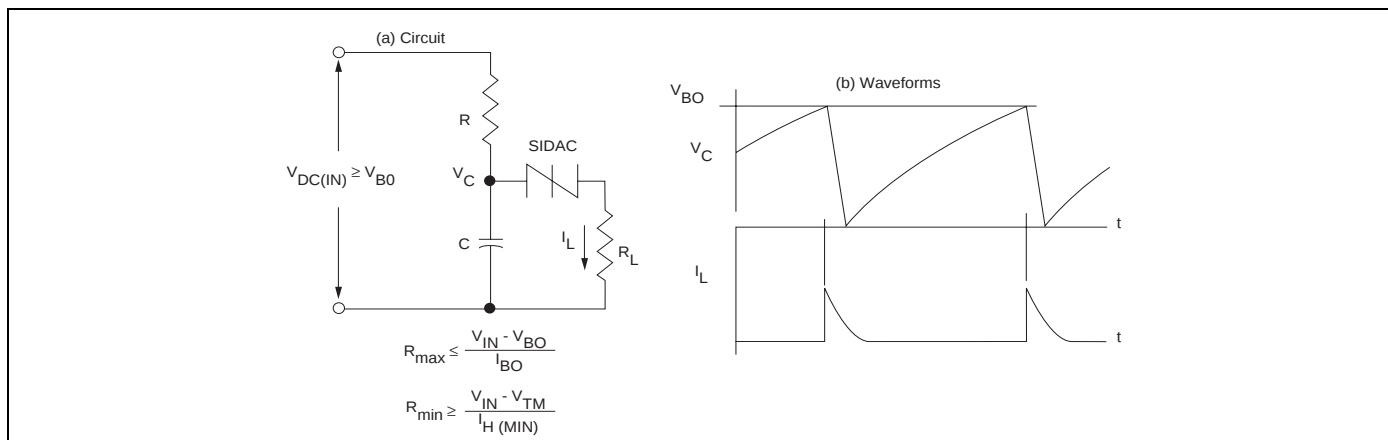


Figure E9.15 Relaxation Oscillator Using a Sidac

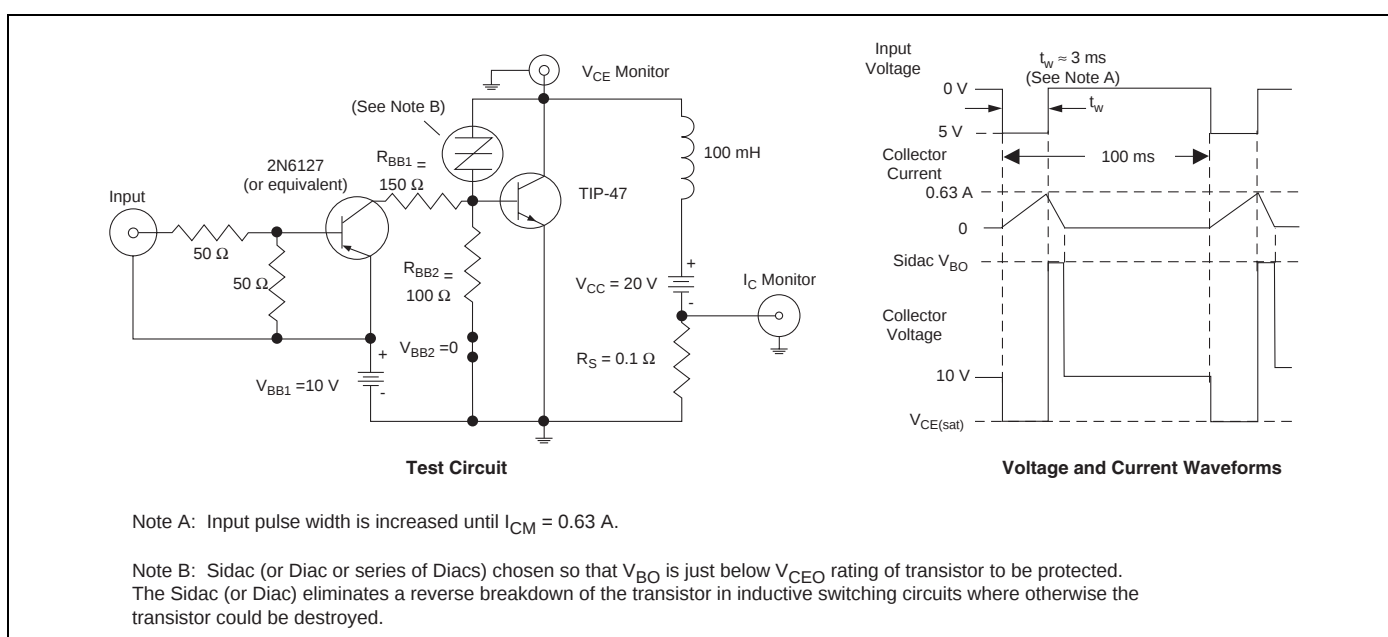


Figure E9.16 Sidac Added to Protect Transistor for Typical Transistor Inductive Load Switching Requirements

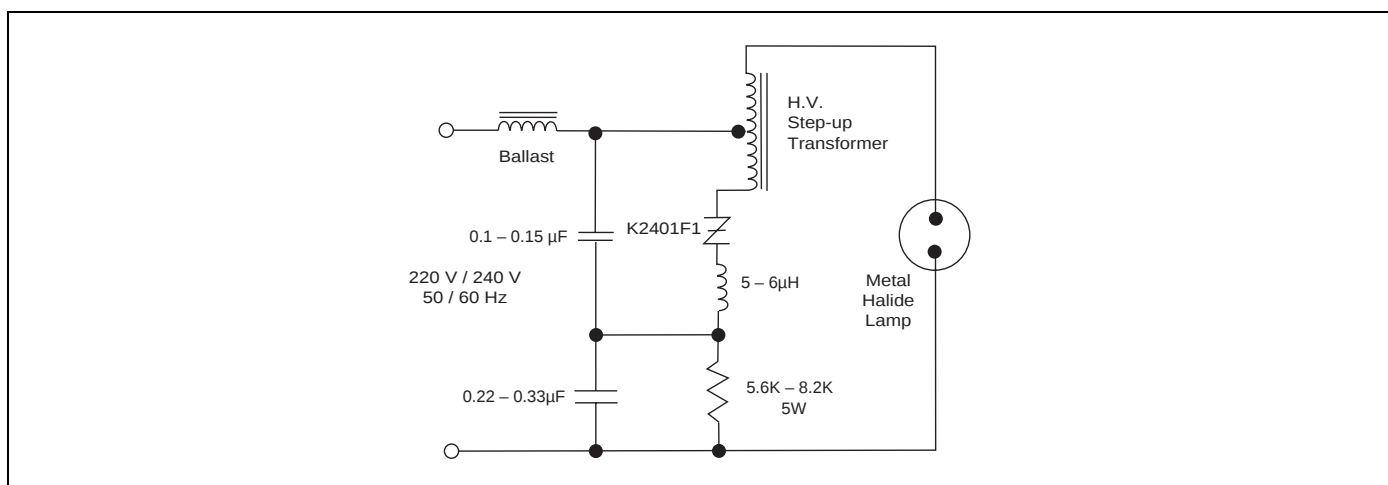


Figure E9.17 Typical Metal Halide Ignitor Circuit